# Onsemi

# FFSH30120ADN-F155

#### Description

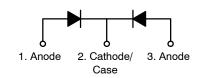
Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### Features

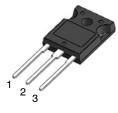
- Max Junction Temperature 175°C
- Avalanche Rated 145 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb-Free, Halogen Free/BFR Free and RoHS Compliant

#### Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

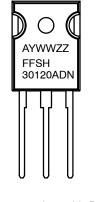


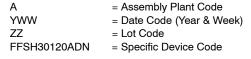
#### Schottky Diode



TO-247-3LD CASE 340CH

### MARKING DIAGRAM





#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

# FFSH30120ADN-F155

Symbol	Parameter	Value	Unit	
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage		1200	V
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)		145	mJ
۱ <sub>F</sub>	Continuous Rectified Forward Current @ T <sub>C</sub> < 148°C		15* / 30**	А
I <sub>F,Max</sub>	Non-Repetitive Peak Forward Surge Current	T <sub>C</sub> = 25°C, 10 μs	1030	А
		T <sub>C</sub> = 150°C, 10 μs	990	А
I <sub>F,SM</sub>	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	125	А
I <sub>F,RM</sub>	Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	50	А
P <sub>TOT</sub>	Power Dissipation	$T_{\rm C} = 25^{\circ}{\rm C}$	195	W
		T <sub>C</sub> = 150°C	32	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		–55 to +175	°C
	TO-247 Mounting Torque, M3 Screw	60	Ncm	

#### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted) (per leg)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

NOTE: \* Per leg, \*\* Per Device.

1.  $E_{AS}$  of 145 mJ is based on starting  $T_J = 25^{\circ}C$ , L = 0.5 mH,  $I_{AS} = 24$  A, V = 150 V.

#### **THERMAL CHARACTERISTICS**

Symbol	Parameter	Value	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max	0.77* / 0.32**	°C/W

NOTE: \* Per leg, \*\* Per Device.

#### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted) (per leg)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 15 A, T <sub>C</sub> = 25°C	-	1.45	1.75	V
		I <sub>F</sub> = 15 A, T <sub>C</sub> = 125°C	-	1.7	2.0	
		I <sub>F</sub> = 15 A, T <sub>C</sub> = 175°C	-	2.0	2.4	
I <sub>R</sub>	Reverse Current	$V_{\rm R}$ = 1200 V, $T_{\rm C}$ = 25°C	-	-	200	μΑ
		$V_{\rm R}$ = 1200 V, $T_{\rm C}$ = 125°C	-	-	300	
		$V_{\rm R}$ = 1200 V, $T_{\rm C}$ = 175°C	-	-	400	
Q <sub>C</sub>	Total Capacitive Charge	V = 800 V	-	95	-	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	936	-	pF
		V <sub>R</sub> = 400 V, f = 100 kHz	-	86	-	1
		V <sub>R</sub> = 800 V, f = 100 kHz	-	68	-	1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

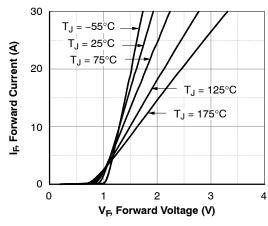
#### **ORDERING INFORMATION**

Part Number	Top Marking	Package	Packing Method	Quantity
FFSH30120ADN-F155	FFSH30120ADN	TO-247-3LD	Tube	30 Units

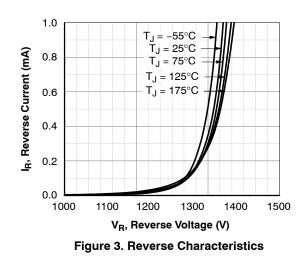
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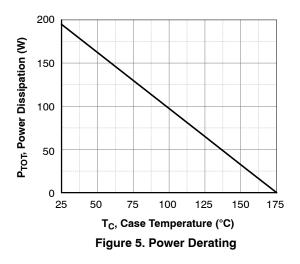
#### **TYPICAL CHARACTERISTICS**

 $(T_J = 25^{\circ}C \text{ UNLESS OTHERWISE NOTED (PER LEG)})$ 









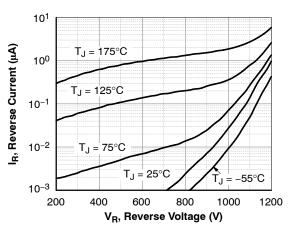
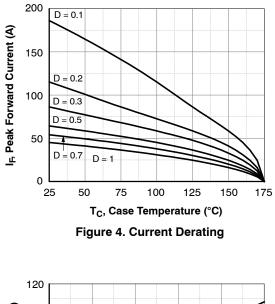
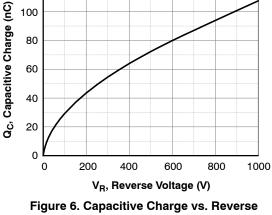


Figure 2. Reverse Characteristics





Voltage

## FFSH30120ADN-F155

**TYPICAL CHARACTERISTICS** (CONTINUED)  $(T_J = 25^{\circ}C \text{ UNLESS OTHERWISE NOTED (PER LEG)})$ 

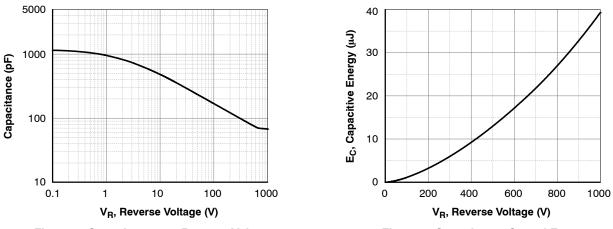


Figure 7. Capacitance vs. Reverse Voltage



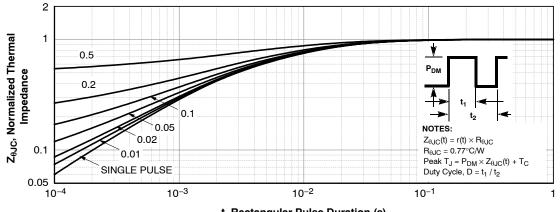
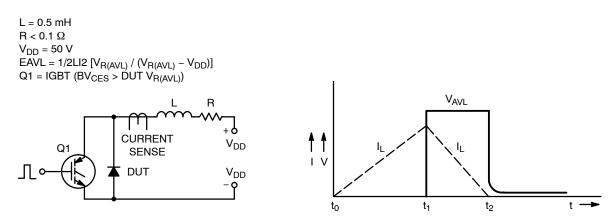




Figure 9. Junction-to-Case Transient Thermal Response Curve

#### **TEST CIRCUIT AND WAVEFORMS**

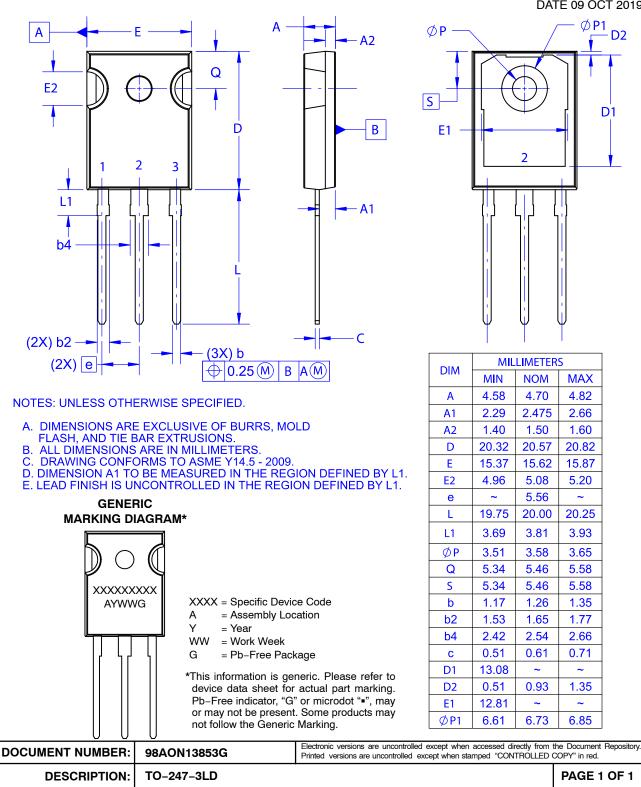






TO-247-3LD CASE 340CH **ISSUE A** 

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